NSN 5962-01-359-5880

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-359-5880

Body Length:

Between 0.640 inches and 0.660 inches

Body Width:

Between 0.540 inches and 0.550 inches

Body Height:

Between 0.080 inches and 0.100 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Low power and high reliability and high performance and w/enable and monolithic and bidirectional and programmed and erasable

Inclosure Material:

Ceramic

Inclosure Configuration:

Pin grid array

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

26 input

Current Rating Per Characteristic:

60.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.0 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

6.00 input picofarads and 10.00 output picofarads

Memory Device Type:

Eeprom

Terminal Type And Quantity:

28 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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